

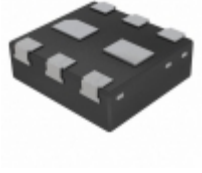
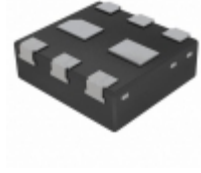
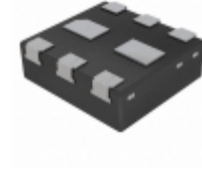

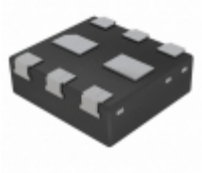
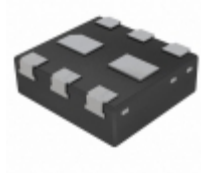
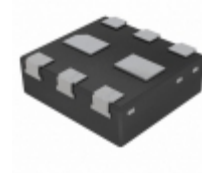
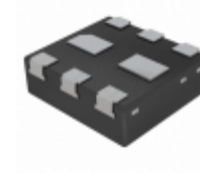
	<h2 style="color: #E67E22;">PMDXB600UNE</h2>	
	Hersteller-Teilenummer:	PMDXB600UNE
	Hersteller / Marke:	Nexperia
	Teil der Beschreibung:	PMDXB600UNE Nexperia USA Inc.
Datenblätter:	 PMDXB600UNE.pdf	
RoHs Status:	Bleifrei / RoHS-konform	
Lagerzustand:	New original, 14861 pcs Stock Available.	
Liefern von:	Hong Kong	
Versandweg:	DHL/Fedex/TNT/UPS/EMS	
<p>Image may be representation. See specs for product details.</p>		

Spezifikationen

Teilenummer	PMDXB600UNE
Hersteller	Nexperia
Beschreibung	PMDXB600UNE Nexperia USA Inc.
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	14861 pcs Stock
Serie	TrenchFET®
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Leistung - max	265mW
Verpackung / Gehäuse	6-XDFN Exposed Pad
Supplier Device-Gehäuse	6-DFN (1.1x1)
Typ FET	2 N-Channel (Dual)
FET-Merkmal	Logic Level Gate
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	600mA
Rds On (Max) @ Id, Vgs	620 mOhm @ 600mA, 4.5V
VGS (th) (Max) @ Id	950mV @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.7nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	21.3pF @ 10V
Verpackung	Tape & Reel (TR)
















































PMDXB600UNE ist neu im Original, Suche PMDXB600UNE Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie PMDXB600UNE Nexperia mit Garantie und Vertrauen.
Anfrage PMDXB600UNE: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>PMDXB950UPE Nichicon MOSFET 2P-CH 20V 0.5A 6DFN</p>	 <p>PMDXB600UNEZ Nexperia MOSFET 2N-CH 20V 0.6A 6DFN</p>	 <p>PMDXB1200UPEZ Nexperia MOSFET 2P-CH 30V 0.41A 6DFN</p>	 <p>PMDT670UPE NXP Semiconductors / Freescale PMDT670UPE NXP</p>
 <p>PMDXB600UNELZ Nexperia 20 V, DUAL N-CHANNEL TRENCH MOSF</p>	 <p>PMDXB950UPE Nexperia MOSFET 2P-CH 20V 0.5A 6DFN</p>	 <p>PMDXB600UNEZ Nichicon MOSFET 2N-CH 20V 0.6A 6DFN</p>	 <p>PMDXB550UNEZ Nexperia MOSFET 2N-CH 30V 0.59A 6DFN</p>

heiße Teile

Mehr

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 GRM1885C1H8R4DZ01D	 IS43DR16640B-25DBLI	 MAKK2520T2R2M	 PMD4001K	 PMD4003K
 D PMD4118OWSR	 PMD5001K	 PMD5002K	 PMD5003K	 PMD505S05HS
  PMD605S3.3HS-R1	  PMD9001D	 PMD9002D	 PMD9003D	 PMD9010D
  PMD9050D	  PMDB75T6	 D PMDPB28UN	 PMDPB42UN	 PMDPB55XP
 PMDPB56XN	 D PMDPB58UPE	  PMDPB65UP	  PMDPB70EN	 PMDPB70XP
 PMDPB80XP	 PMDT290UCE	  PMDT290UNE	  PMDT670UPE	 PMDXB950UPE
 PMDXB950UPE	 PMDKZ13AKUP6	  SI7886DP-T1-GE3	 D SLF12575T-680M2RO-PF	 SMF48A_R1_00001
  SN74S30N	  SP723ABT	 PMDKZ13AKUP6	  V300C28C150BN2	 ZM33064N8

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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